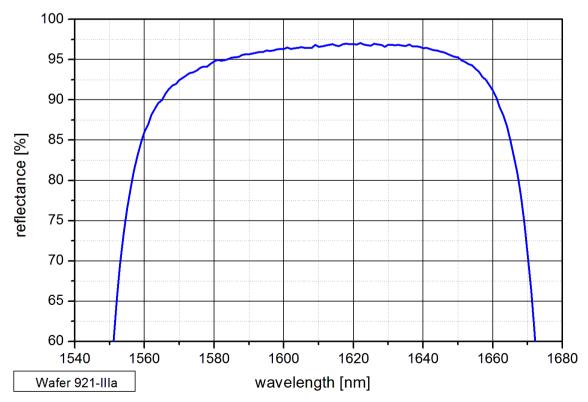


SAM™ Data Sheet SAM-1645-4-2ps-x, λ = 1645 nm

Laser wavelength	λ = 1645 nm
High reflection band	λ = 1580 1650 nm
Absorbance	$A_0 = 4 \%$
Modulation depth	∆R = 2.4 %
Non-saturable loss	A _{ns} = 1.6 %
Saturation fluence	Φ_{sat} = 110 µJ/cm ²
Relaxation time constant	τ ~ 2 ps
Damage threshold	Φ = 1.5 mJ/cm ²
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer
Mounting option x denotes the $\mathbf{x} = 0$	type of mounting as follows:

$\mathbf{x} = 0$	unnounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.0 mm $arnothing$
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance





Dispersion (GVD)

